
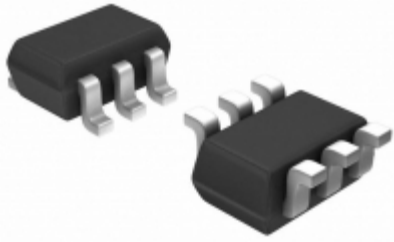








	<h2>SI1406DH-T1-E3</h2>
	<p>Hersteller-Teilenummer: SI1406DH-T1-E3</p> <hr/> <p>Hersteller / Marke: Vishay / Siliconix</p> <hr/> <p>Teil der Beschreibung: MOSFET N-CH 20V 3.1A SC70-6</p> <hr/> <p>Datenblätter:  SI1406DH-T1-E3.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 142802 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI1406DH-T1-E3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 20V 3.1A SC70-6
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	142802 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	6-TSSOP, SC-88, SOT-363
Supplier Device-Gehäuse	SC-70-6 (SOT-363)
Verlustleistung (max)	1W (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	3.1A (Ta)
Rds On (Max) @ Id, Vgs	65 mOhm @ 3.9A, 4.5V
VGS (th) (Max) @ Id	1.2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	7.5nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Tape & Reel (TR)














































SI1406DH-T1-E3 ist neu im Original, Suche SI1406DH-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI1406DH-T1-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI1406DH-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI1406DH VISHAY SI1406DH VISHAY</p>	 <p>SI1406DH-T1-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 20V 3.1A SC70-6</p>	 <p>SI1406DH-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 20V 3.1A SC-70-6</p>	 <p>SI1405DL-T1-E3 Electro-Films (EFI) / Vishay MOSFET P-CH 8V 1.6A SC-70-6</p>
 <p>SI1406DH-T1 VISHAY SI1406DH-T1 VISHAY</p>	 <p>SI1407DL VISHAY SI1407DL VISHAY</p>	 <p>SI1406DH-T1-GE3 Vishay / Siliconix MOSFET N-CH 20V 3.1A SC-70-6</p>	 <p>SI1407DL-T1 SILICON SI1407DL-T1 SILICON</p>

heiße Teile

Mehr

 SI1403BDL-T1-E3	 SI1403BDL-T1-E3	 SI1403BDL-T1-GE3	 SI1403BDL-T1-GE3	 SI1403CDL-T1-GE3
 SI1403CDL-T1-GE3	 SI1403DL	 SI1403DL-T1	 SI1403DL-T1-E3	 SI1403DL-T1-GE3
 SI1404BDH-T1-E3	 SI1404BDH-T1-E3	 SI1404DH-T1	 SI1404DH-T1-E3	 SI1404DH-T1-GE3
 SI1404DL-T1-GE3	 SI1405BDH-T1-E3	 SI1405BDH-T1-E3	 SI1405BDH-T1-GE3	 SI1405BDH-T1-GE3
 SI1405DL-T1	 SI1405DL-T1-E3	 SI1405DL-T1-E3	 SI1406DH	 SI1406DH-T1
 SI1406DH-T1-E3	 SI1406DH-T1-GE3	 SI1406DH-T1-GE3	 SI1407DL	 SI1407DL-T1
 SI1407DL-T1-E3	 SI1407DL-T1-GE3	 SI1410EDH	 SI1410EDH-T1	 SI1410EDH-T1-E3
 SI1410EDH-T1-E3	 SI1410EDH-T1-GE3	 SI1413DH-T1	 SI1413EDH	 SI1413EDH-T1
 SI1413EDH-T1-E3	 SI1413EDH-T1-E3	 SI1413EDH-T1-GE3	 SI1413EDH-T1-GE3	 SI1414DH-T1-GE3
 SI1414DH-T1-GE3	 SI1416EDH-T1-GE3	 SI1416EDH-T1-GE3	 SI1417DH-T1-E3	 SI1417DH-T1-GE3

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